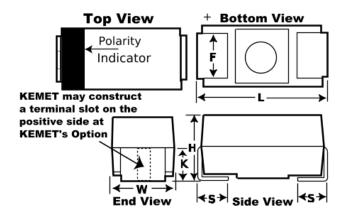


T495T336M006ZTE800

Obsolete

B45190R, Tantalum, MnO2 Tantalum, 33 uF, 20%, 6.3 VDC, SMD, Molded, Low Profile, Low ESR, Surge Robust, 800 mOhms, 3528, Height Max = 1.2mm



General Information		
Series	B45190R	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, Low Profile, Low ESR, Surge Robust	
Features	Low Profile, Low ESR, Surge Robust	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45190R1336M209.	

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.2mm MAX
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1mm TYP

Specifications	
Capacitance	33 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
Resistance	0.8 Ohms (100kHz)
Ripple Current	310 mAmps (25C), 279 mAmps (85C), 124 mAmps (125C)
Leakage Current	2.1uA

Packaging Specifications			
Packaging	T&R, 178mm		
Packaging Quantity	2500		

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